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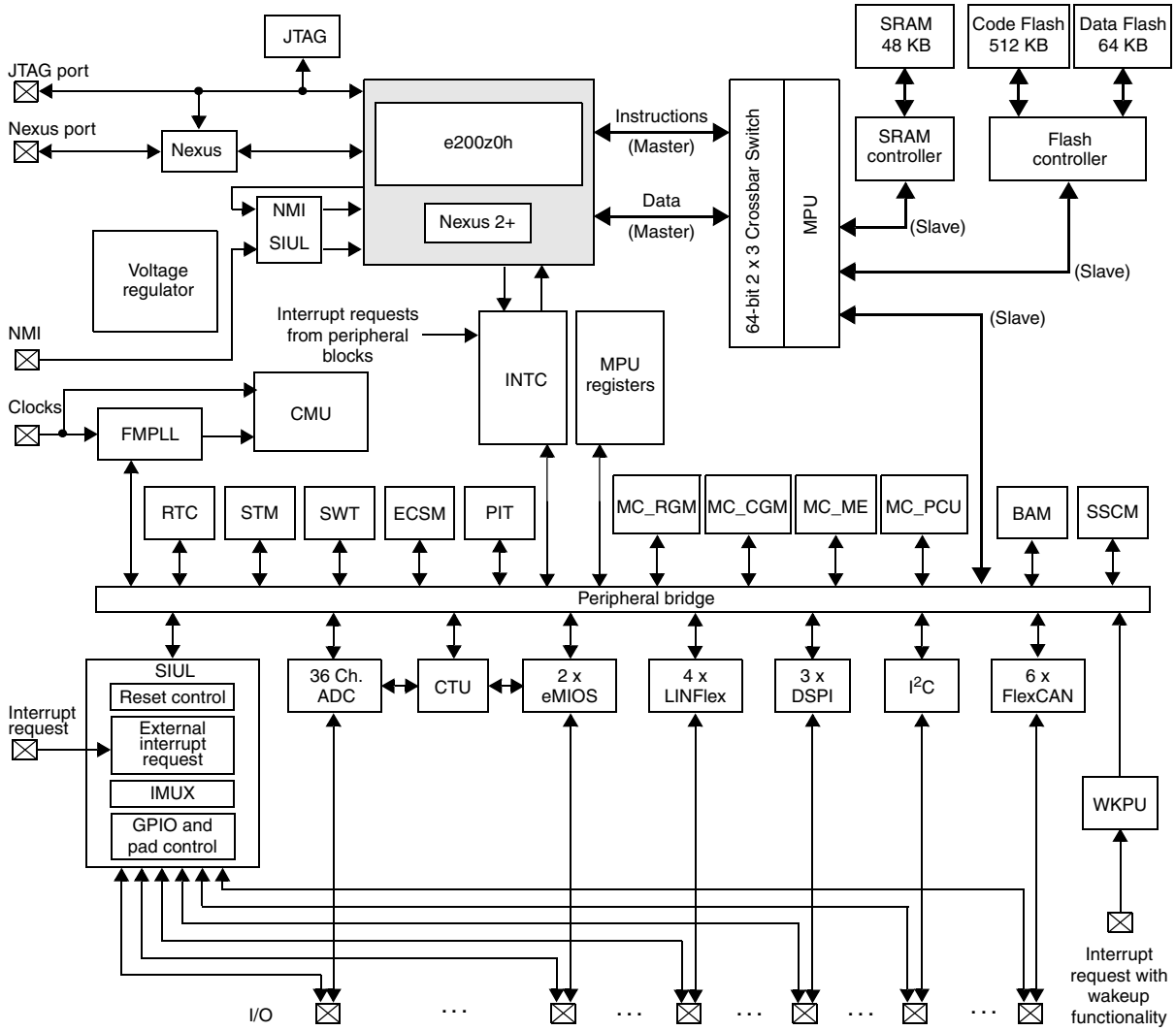
Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, I²C, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	79
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 28x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5604bamll6r

1.3 Block diagram

Figure 1 shows a top-level block diagram of the MPC5604B/C device series.



Legend:

ADC	Analog-to-Digital Converter
BAM	Boot Assist Module
FlexCAN	Controller Area Network
CMU	Clock Monitor Unit
CTU	Cross Triggering Unit
DSPI	Deserial Serial Peripheral Interface
eMIOS	Enhanced Modular Input Output System
FMPLL	Frequency-Modulated Phase-Locked Loop
I^2C	Inter-integrated Circuit Bus
IMUX	Internal Multiplexer
INTC	Interrupt Controller
JTAG	JTAG controller
LINFlex	Serial Communication Interface (LIN support)
ECSM	Error Correction Status Module
MC_CGM	Clock Generation Module
MC_ME	Mode Entry Module
MC_PCU	Power Control Unit
MC_RGM	Reset Generation Module
MPU	Memory Protection Unit
Nexus	Nexus Development Interface (NDI) Level
NMI	Non-Maskable Interrupt
PIT	Periodic Interrupt Timer
RTC	Real-Time Clock
SIUL	System Integration Unit Lite
SRAM	Static Random-Access Memory
SSCM	System Status Configuration Module
STM	System Timer Module
SWT	Software Watchdog Timer
WKPU	Wakeup Unit

Figure 1. Block diagram

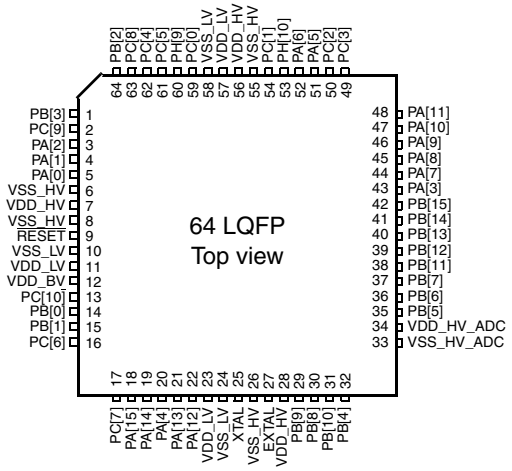


Figure 2. MPC560xB LQFP 64-pin configuration

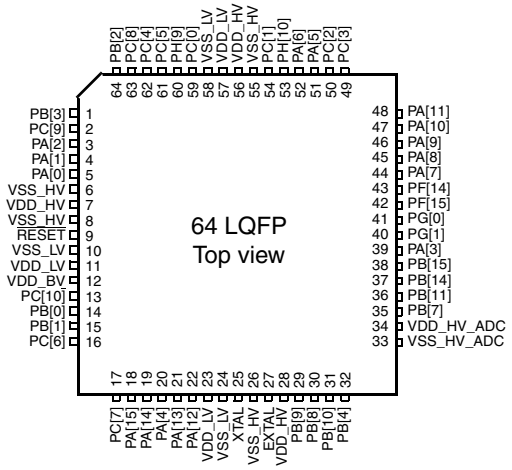


Figure 3. MPC560xC LQFP 64-pin configuration

I = Input only with analog feature[1]
J = Input/Output ('S' pad) with analog feature
X = Oscillator

2.5 System pins

The system pins are listed in Table 4.

Table 4. System pin descriptions

System pin	Function	I/O direction	Pad type	RESET configuration	Pin number			
					64 LQFP[1]	100 LQFP	144 LQFP	208 MAPBGA[2]
$\overline{\text{RESET}}$	Bidirectional reset with Schmitt-Trigger characteristics and noise filter.	I/O	M	Input, weak pull-up only after PHASE2	9	17	21	J1
EXTAL	Analog output of the oscillator amplifier circuit, when the oscillator is not in bypass mode. Analog input for the clock generator when the oscillator is in bypass mode.[3]	I/O	X	Tristate	27	36	50	N8
XTAL	Analog input of the oscillator amplifier circuit. Needs to be grounded if oscillator is used in bypass mode.[3]	I	X	Tristate	25	34	48	P8

1 Pin numbers apply to both the MPC560xB and MPC560xC packages.
2 208 MAPBGA available only as development package for Nexus2+
3 See the relevant section of the datasheet

2.6 Functional ports

The functional port pins are listed in Table 5.

Table 5. Functional port pin descriptions

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PA[0]	PCR[0]	AF0 AF1 AF2 AF3 —	GPIO[0] E0UC[0] CLKOUT — WKPU[19][4]	SIUL eMIOS_0 CGL — WKPU	I/O I/O O — I	M	Tristate	5	5	12	16	G4

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PA[8]	PCR[8]	AF0 AF1 AF2 AF3 — N/A[6] —	GPIO[8] E0UC[8] — — EIRQ[3] ABS[0] LIN3RX	SIUL eMIOS_0 — — SIUL BAM LINFlex_3	I/O I/O — — I I I	S	Input, weak pull-up	45	45	72	105	C16
PA[9]	PCR[9]	AF0 AF1 AF2 AF3 N/A[6]	GPIO[9] E0UC[9] — — FAB	SIUL eMIOS_0 — — BAM	I/O I/O — — I	S	Pull-down	46	46	73	106	C15
PA[10]	PCR[10]	AF0 AF1 AF2 AF3	GPIO[10] E0UC[10] SDA —	SIUL eMIOS_0 I2C_0 —	I/O I/O I/O —	S	Tristate	47	47	74	107	B16
PA[11]	PCR[11]	AF0 AF1 AF2 AF3	GPIO[11] E0UC[11] SCL —	SIUL eMIOS_0 I2C_0 —	I/O I/O I/O —	S	Tristate	48	48	75	108	B15
PA[12]	PCR[12]	AF0 AF1 AF2 AF3 —	GPIO[12] — — — SIN_0	SIUL — — — DSPI0	I/O — — — I	S	Tristate	22	22	31	45	T7
PA[13]	PCR[13]	AF0 AF1 AF2 AF3	GPIO[13] SOUT_0 — —	SIUL DSPI_0 — —	I/O O — —	M	Tristate	21	21	30	44	R7
PA[14]	PCR[14]	AF0 AF1 AF2 AF3 —	GPIO[14] SCK_0 CS0_0 — EIRQ[4]	SIUL DSPI_0 DSPI_0 — SIUL	I/O I/O I/O — I	M	Tristate	19	19	28	42	P6
PA[15]	PCR[15]	AF0 AF1 AF2 AF3 —	GPIO[15] CS0_0 SCK_0 — WKPU[10][4]	SIUL DSPI_0 DSPI_0 — WKPU	I/O I/O I/O — I	M	Tristate	18	18	27	40	R6

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PB[8]	PCR[24]	AF0 AF1 AF2 AF3 — —	GPIO[24] — — — ANS[0] OSC32K_XTAL[7]	SIUL — — — ADC SXOSC	I — — — I I/O	I	Tristate	30	30	39	53	R9
PB[9]	PCR[25]	AF0 AF1 AF2 AF3 — —	GPIO[25] — — — ANS[1] OSC32K_EXTAL[7]	SIUL — — — ADC SXOSC	I — — — I I/O	I	Tristate	29	29	38	52	T9
PB[10]	PCR[26]	AF0 AF1 AF2 AF3 — —	GPIO[26] — — — ANS[2] WKPU[8][4]	SIUL — — — ADC WKPU	I/O — — — I I	J	Tristate	31	31	40	54	P9
PB[11][8]	PCR[27]	AF0 AF1 AF2 AF3 —	GPIO[27] E0UC[3] — CS0_0 ANS[3]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — I/O I	J	Tristate	38	36	59	81	N13
PB[12]	PCR[28]	AF0 AF1 AF2 AF3 —	GPIO[28] E0UC[4] — CS1_0 ANX[0]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	39	—	61	83	M16
PB[13]	PCR[29]	AF0 AF1 AF2 AF3 —	GPIO[29] E0UC[5] — CS2_0 ANX[1]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	40	—	63	85	M13
PB[14]	PCR[30]	AF0 AF1 AF2 AF3 —	GPIO[30] E0UC[6] — CS3_0 ANX[2]	SIUL eMIOS_0 — DSPI_0 ADC	I/O I/O — O I	J	Tristate	41	37	65	87	L16

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PF[8]	PCR[88]	AF0 AF1 AF2 AF3	GPIO[88] CAN3TX[14] CS4_0 CAN2TX[15]	SIUL FlexCAN_3 DSPI_0 FlexCAN_2	I/O O O O	M	Tristate	—	—	—	34	P1
PF[9]	PCR[89]	AF0 AF1 AF2 AF3 — —	GPIO[89] — CS5_0 — CAN2RX[15] CAN3RX[14]	SIUL — DSPI_0 — FlexCAN_2 FlexCAN_3	I/O — O — I I	S	Tristate	—	—	—	33	N2
PF[10]	PCR[90]	AF0 AF1 AF2 AF3	GPIO[90] — — —	SIUL — — —	I/O — — —	M	Tristate	—	—	—	38	R3
PF[11]	PCR[91]	AF0 AF1 AF2 AF3 —	GPIO[91] — — — WKPU[15][4]	SIUL — — — WKPU	I/O — — — I	S	Tristate	—	—	—	39	R4
PF[12]	PCR[92]	AF0 AF1 AF2 AF3	GPIO[92] E1UC[25] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	35	R1
PF[13]	PCR[93]	AF0 AF1 AF2 AF3 —	GPIO[93] E1UC[26] — — WKPU[16][4]	SIUL eMIOS_1 — — WKPU	I/O I/O — — I	S	Tristate	—	—	—	41	T6
PF[14]	PCR[94]	AF0 AF1 AF2 AF3	GPIO[94] CAN4TX[11] E1UC[27] CAN1TX	SIUL FlexCAN_4 eMIOS_1 FlexCAN_4	I/O O I/O O	M	Tristate	—	43	—	102	D14
PF[15]	PCR[95]	AF0 AF1 AF2 AF3 — — —	GPIO[95] — — — CAN1RX CAN4RX[11] EIRQ[13]	SIUL — — — FlexCAN_1 FlexCAN_4 SIUL	I/O — — — I I I	S	Tristate	—	42	—	101	E15

Table 5. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function[1]	Function	Peripheral	I/O direction[2]	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA[3]
PH[2]	PCR[114]	AF0 AF1 AF2 AF3	GPIO[114] E1UC[4] SCK_1 —	SIUL eMIOS_1 DSPI_1 —	I/O I/O I/O —	M	Tristate	—	—	—	95	F16
PH[3]	PCR[115]	AF0 AF1 AF2 AF3	GPIO[115] E1UC[5] CS0_1 —	SIUL eMIOS_1 DSPI_1 —	I/O I/O I/O —	M	Tristate	—	—	—	96	F15
PH[4]	PCR[116]	AF0 AF1 AF2 AF3	GPIO[116] E1UC[6] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	134	A6
PH[5]	PCR[117]	AF0 AF1 AF2 AF3	GPIO[117] E1UC[7] — —	SIUL eMIOS_1 — —	I/O I/O — —	S	Tristate	—	—	—	135	B6
PH[6]	PCR[118]	AF0 AF1 AF2 AF3	GPIO[118] E1UC[8] — MA[2]	SIUL eMIOS_1 — ADC	I/O I/O — O	M	Tristate	—	—	—	136	D5
PH[7]	PCR[119]	AF0 AF1 AF2 AF3	GPIO[119] E1UC[9] CS3_2 MA[1]	SIUL eMIOS_1 DSPI_2 ADC	I/O I/O O O	M	Tristate	—	—	—	137	C5
PH[8]	PCR[120]	AF0 AF1 AF2 AF3	GPIO[120] E1UC[10] CS2_2 MA[0]	SIUL eMIOS_1 DSPI_2 ADC	I/O I/O O O	M	Tristate	—	—	—	138	A5
PH[9][9]	PCR[121]	AF0 AF1 AF2 AF3	GPIO[121] — TCK —	SIUL — JTAGC —	I/O — I —	S	Input, weak pull-up	60	60	88	127	B8
PH[10][9]	PCR[122]	AF0 AF1 AF2 AF3	GPIO[122] — TMS —	SIUL — JTAGC —	I/O — I —	S	Input, weak pull-up	53	53	81	120	B9

Table 17. SLOW configuration output buffer electrical characteristics

Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
V_{OH}	CC	P	Output high level SLOW configuration	Push Pull	I_{OH} = –2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	$0.8V_{DD}$	—	—	V
		C			I_{OH} = –2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 1[2]	$0.8V_{DD}$	—	—	
		C			I_{OH} = –1 mA, V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	V_{DD}–0.8	—	—	
V_{OL}	CC	P	Output low level SLOW configuration	Push Pull	I_{OL} = 2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	—	—	$0.1V_{DD}$	V
		C			I_{OL} = 2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 1[2]	—	—	$0.1V_{DD}$	
		C			I_{OL} = 1 mA, V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	—	—	0.5	

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

2 The configuration PAD3V5 = 1 when V_{DD} = 5 V is only a transient configuration during power-up. All pads but RESET and Nexus output (MDOx, EVTO, MCKO) are configured in input or in high impedance state.

Table 18. MEDIUM configuration output buffer electrical characteristics

Symbol		C	Parameter	Conditions[1]		Value			Unit
						Min	Typ	Max	
V_{OH}	CC	C	Output high level MEDIUM configuration	Push Pull	I_{OH} = –3.8 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	$0.8V_{DD}$	—	—	V
		P			I_{OH} = –2 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0 (recommended)	$0.8V_{DD}$	—	—	
		C			I_{OH} = –1 mA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 1[2]	$0.8V_{DD}$	—	—	
		C			I_{OH} = –1 mA, V_{DD} = 3.3 V ± 10%, PAD3V5V = 1 (recommended)	V_{DD}–0.8	—	—	
		C			I_{OH} = –100 µA, V_{DD} = 5.0 V ± 10%, PAD3V5V = 0	$0.8V_{DD}$	—	—	

Table 23. I/O weight[1] (continued)

Supply segment			Pad	144/100 LQFP				64 LQFP			
				Weight 5 V		Weight 3.3 V		Weight 5 V		Weight 3.3 V	
144 LQFP	100 LQFP	64 LQFP[2]		SRC[3] = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1
1	—	—	PG[9]	9%	—	10%	—	—	—	—	—
	—	—	PG[8]	9%	—	11%	—	—	—	—	—
	1	—	PC[11]	9%	—	11%	—	—	—	—	—
		1	PC[10]	9%	13%	11%	12%	9%	13%	11%	12%
	—	—	PG[7]	10%	14%	11%	12%	—	—	—	—
	—	—	PG[6]	10%	14%	12%	12%	—	—	—	—
	1	1	PB[0]	10%	14%	12%	12%	10%	14%	12%	12%
			PB[1]	10%	—	12%	—	10%	—	12%	—
	—	—	PF[9]	10%	—	12%	—	—	—	—	—
	—	—	PF[8]	10%	15%	12%	13%	—	—	—	—
	—	—	PF[12]	10%	15%	12%	13%	—	—	—	—
	1	1	PC[6]	10%	—	12%	—	10%	—	12%	—
			PC[7]	10%	—	12%	—	10%	—	12%	—
	—	—	PF[10]	10%	14%	12%	12%	—	—	—	—
	—	—	PF[11]	10%	—	11%	—	—	—	—	—
	1	1	PA[15]	9%	12%	10%	11%	9%	12%	10%	11%
	—	—	PF[13]	8%	—	10%	—	—	—	—	—
	1	1	PA[14]	8%	11%	9%	10%	8%	11%	9%	10%
			PA[4]	8%	—	9%	—	8%	—	9%	—
			PA[13]	7%	10%	9%	9%	7%	10%	9%	9%
			PA[12]	7%	—	8%	—	7%	—	8%	—

Table 23. I/O weight[1] (continued)

Supply segment			Pad	144/100 LQFP				64 LQFP			
				Weight 5 V		Weight 3.3 V		Weight 5 V		Weight 3.3 V	
144 LQFP	100 LQFP	64 LQFP[2]		SRC[3] = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1
2	2	2	PB[9]	1%	—	1%	—	1%	—	1%	—
			PB[8]	1%	—	1%	—	1%	—	1%	—
			PB[10]	6%	—	7%	—	6%	—	7%	—
	—	—	PF[0]	6%	—	7%	—	—	—	—	—
	—	—	PF[1]	7%	—	8%	—	—	—	—	—
	—	—	PF[2]	7%	—	8%	—	—	—	—	—
	—	—	PF[3]	7%	—	9%	—	—	—	—	—
	—	—	PF[4]	8%	—	9%	—	—	—	—	—
	—	—	PF[5]	8%	—	10%	—	—	—	—	—
	—	—	PF[6]	8%	—	10%	—	—	—	—	—
	—	—	PF[7]	9%	—	10%	—	—	—	—	—
	2	—	PD[0]	1%	—	1%	—	—	—	—	—
		—	PD[1]	1%	—	1%	—	—	—	—	—
		—	PD[2]	1%	—	1%	—	—	—	—	—
		—	PD[3]	1%	—	1%	—	—	—	—	—
		—	PD[4]	1%	—	1%	—	—	—	—	—
		—	PD[5]	1%	—	1%	—	—	—	—	—
		—	PD[6]	1%	—	1%	—	—	—	—	—
		—	PD[7]	1%	—	1%	—	—	—	—	—
		—	PD[8]	1%	—	1%	—	—	—	—	—
		2	PB[4]	1%	—	1%	—	1%	—	1%	—
			PB[5]	1%	—	1%	—	1%	—	2%	—
			PB[6]	1%	—	1%	—	1%	—	2%	—
			PB[7]	1%	—	1%	—	1%	—	2%	—
		—	PD[9]	1%	—	1%	—	—	—	—	—
		—	PD[10]	1%	—	1%	—	—	—	—	—
		—	PD[11]	1%	—	1%	—	—	—	—	—
		2	PB[11]	11%	—	13%	—	17%	—	21%	—
		—	PD[12]	11%	—	13%	—	—	—	—	—
		2	PB[12]	11%	—	13%	—	18%	—	21%	—
		—	PD[13]	10%	—	12%	—	—	—	—	—

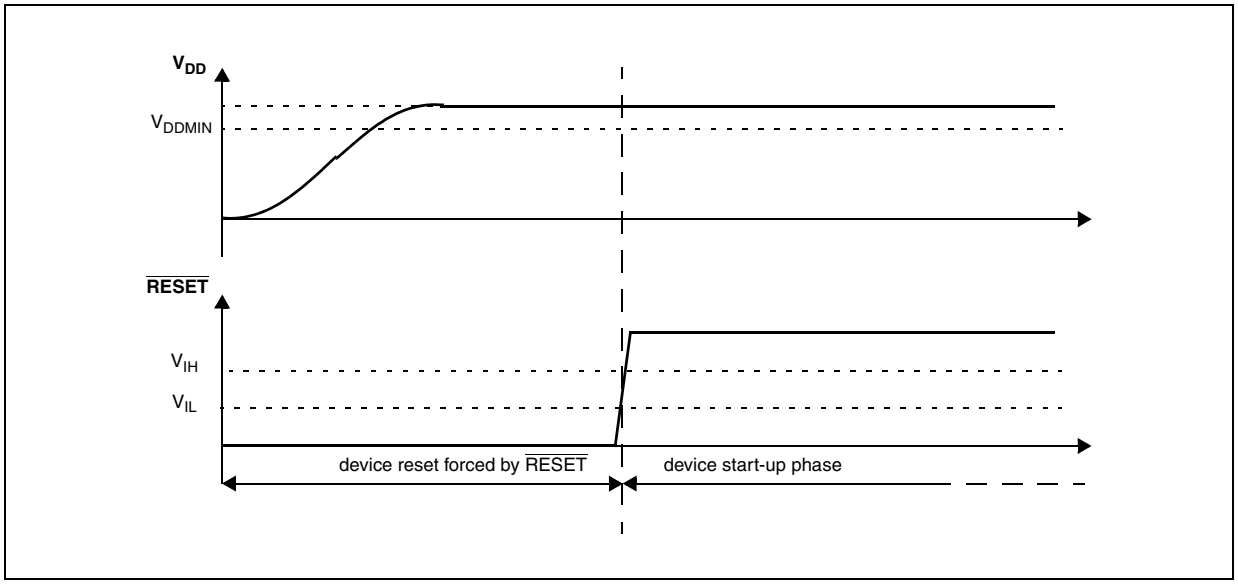


Figure 8. Start-up reset requirements

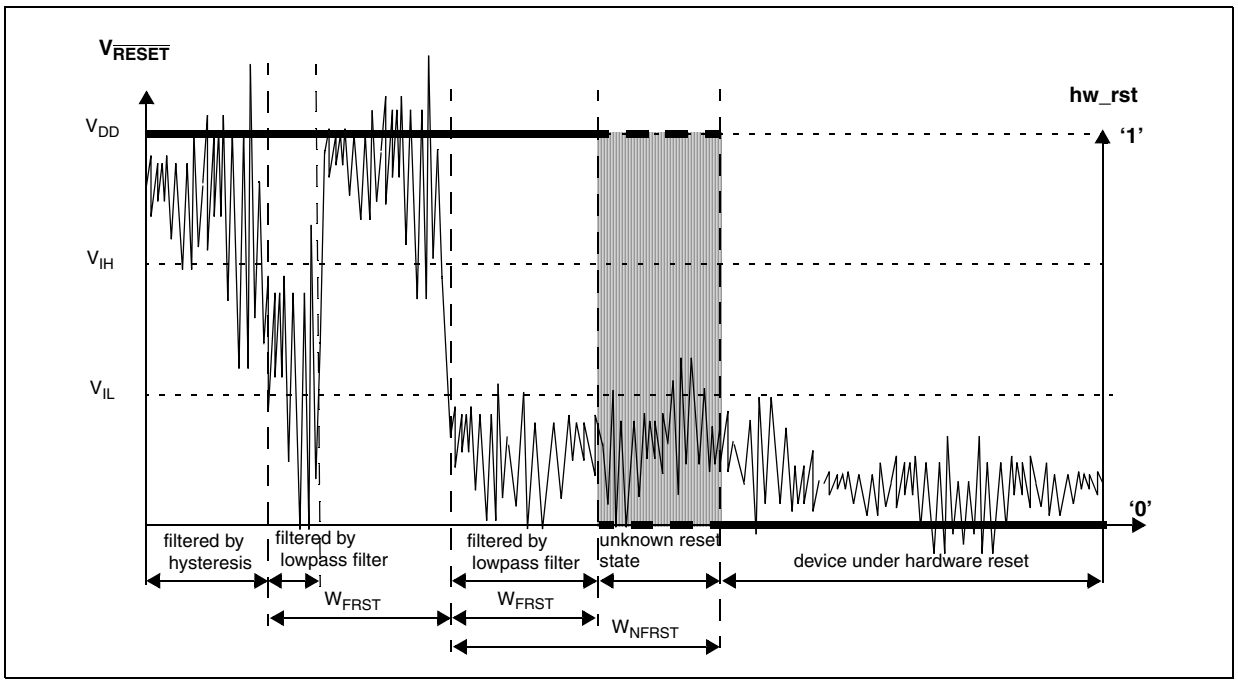


Figure 9. Noise filtering on reset signal

Table 24. Reset electrical characteristics

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
V_{IH}	SR	P	Input High Level CMOS (Schmitt Trigger)	—	$0.65V_{DD}$	—	$V_{DD}+0.4$	V

[5] Only for the “P” classification: Data and Code Flash in Normal Power. Code fetched from RAM: Serial IPs CAN and LIN in loop back mode, DSPI as Master, PLL as system Clock (4 x Multiplier) peripherals on (eMIOS/CTU/ADC) and running at max frequency, periodic SW/WDG timer reset enabled.

[6] Data Flash Power Down. Code Flash in Low Power. SIRC (128 kHz) and FIRC (16 MHz) on. 10 MHz XTAL clock. FlexCAN: instances: 0, 1, 2 ON (clocked but not reception or transmission), instances: 4, 5, 6 clock gated. LINFlex: instances: 0, 1, 2 ON (clocked but not reception or transmission), instance: 3 clock gated. eMIOS: instance: 0 ON (16 channels on PA[0]–PA[11] and PC[12]–PC[15]) with PWM 20 kHz, instance: 1 clock gated. DSPI: instance: 0 (clocked but no communication). RTC/API ON. PIT ON. STM ON. ADC ON but not conversion except 2 analog watchdog.

[7] Only for the “P” classification: No clock, FIRC (16 MHz) off, SIRC (128 kHz) on, PLL off, HPvreg off, ULPVreg/LPVreg on. All possible peripherals off and clock gated. Flash in power down mode.

[8] When going from RUN to STOP mode and the core consumption is > 6 mA, it is normal operation for the main regulator module to be kept on by the on-chip current monitoring circuit. This is most likely to occur with junction temperatures exceeding 125 °C and under these circumstances, it is possible for the current to initially exceed the maximum STOP specification by up to 2 mA. After entering stop, the application junction temperature will reduce to the ambient level and the main regulator will be automatically switched off when the load current is below 6 mA.

[9] Only for the “P” classification: ULPreg on, HP/LPVreg off, 32 KB RAM on, device configured for minimum consumption, all possible modules switched off.

[10] ULPreg on, HP/LPVreg off, 8 KB RAM on, device configured for minimum consumption, all possible modules switched off.

2.19 Flash memory electrical characteristics

2.19.1 Program/Erase characteristics

Table 28 shows the program and erase characteristics.

Table 28. Program and erase specifications

Symbol		C	Parameter	Value				Unit
				Min	Typ[1]	Initial max[2]	Max[3]	
$T_{dwprogram}$	CC	C	Double word (64 bits) program time[4]	—	22	50	500	µs
$T_{16Kpperase}$			16 KB block preprogram and erase time	—	300	500	5000	ms
$T_{32Kpperase}$			32 KB block preprogram and erase time	—	400	600	5000	ms
$T_{128Kpperase}$			128 KB block preprogram and erase time	—	800	1300	7500	ms
T_{esus}	CC	D	Erase suspend latency	—	—	30	30	µs

[1] Typical program and erase times assume nominal supply values and operation at 25 °C.

[2] Initial factory condition: < 100 program/erase cycles, 25 °C, typical supply voltage.

[3] The maximum program and erase times occur after the specified number of program/erase cycles. These maximum values are characterized but not guaranteed.

[4] Actual hardware programming times. This does not include software overhead.

Table 29. Flash module life

Symbol		C	Parameter	Conditions	Value			Unit
					Min	Typ	Max	
P/E	CC	C	Number of program/erase cycles per block over the operating temperature range (T_J)	16 KB blocks	100,000	—	—	cycles
				32 KB blocks	10,000	100,000	—	
				128 KB blocks	1,000	100,000	—	
Retention	CC	C	Minimum data retention at 85 °C average ambient temperature[1]	Blocks with 0–1,000 P/E cycles	20	—	—	years
				Blocks with 1,001–10,000 P/E cycles	10	—	—	
				Blocks with 10,001–100,000 P/E cycles	5	—	—	

1 Ambient temperature averaged over duration of application, not to exceed recommended product operating temperature range.

ECC circuitry provides correction of single bit faults and is used to improve further automotive reliability results. Some units will experience single bit corrections throughout the life of the product with no impact to product reliability.

Table 30. Flash read access timing

Symbol		C	Parameter	Conditions[1]	Max	Unit
f_{READ}	CC	P	Maximum frequency for Flash reading	2 wait states	64	MHz
		C		1 wait state	40	
		C		0 wait states	20	

1 V_{DD} = 3.3 V ± 10% / 5.0 V ± 10%, T_A = –40 to 125 °C, unless otherwise specified

2.19.2 Flash power supply DC characteristics

Table 31 shows the power supply DC characteristics on external supply.

Table 31. Flash memory power supply DC electrical characteristics

Symbol		C	Parameter	Conditions[1]	Value			Unit
					Min	Typ	Max	
I_{FREAD}[2]	CC	D	Sum of the current consumption on VDD_HV and VDD_BV on read access	Code flash memory module read f_{CPU} = 64 MHz[3]	—	15	33	mA
				Data flash memory module read f_{CPU} = 64 MHz[3]	—	15	33	

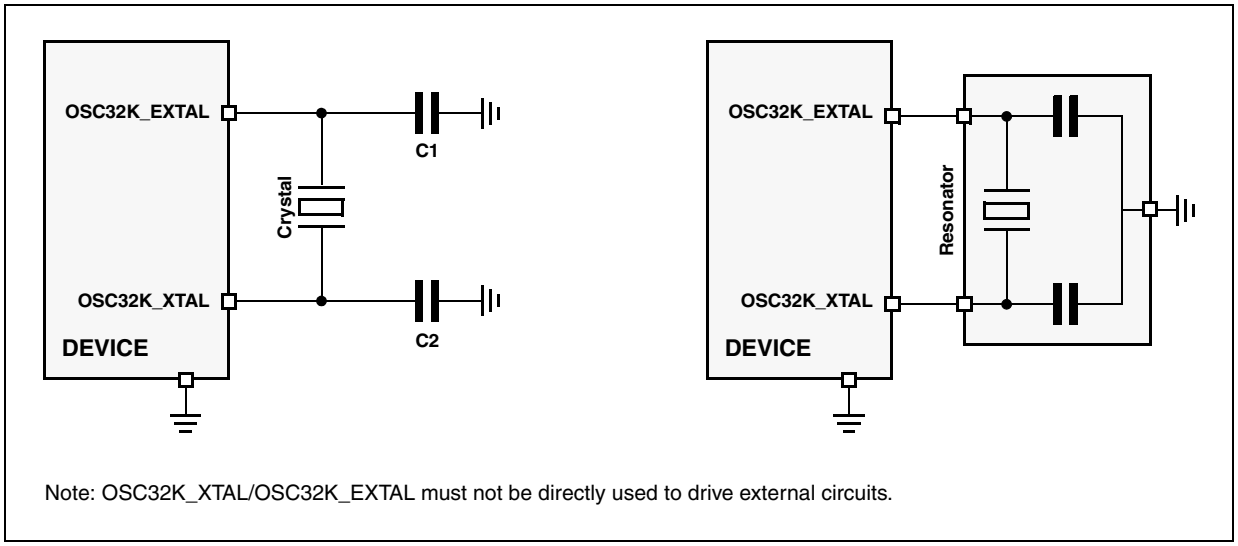


Figure 16. Crystal oscillator and resonator connection scheme

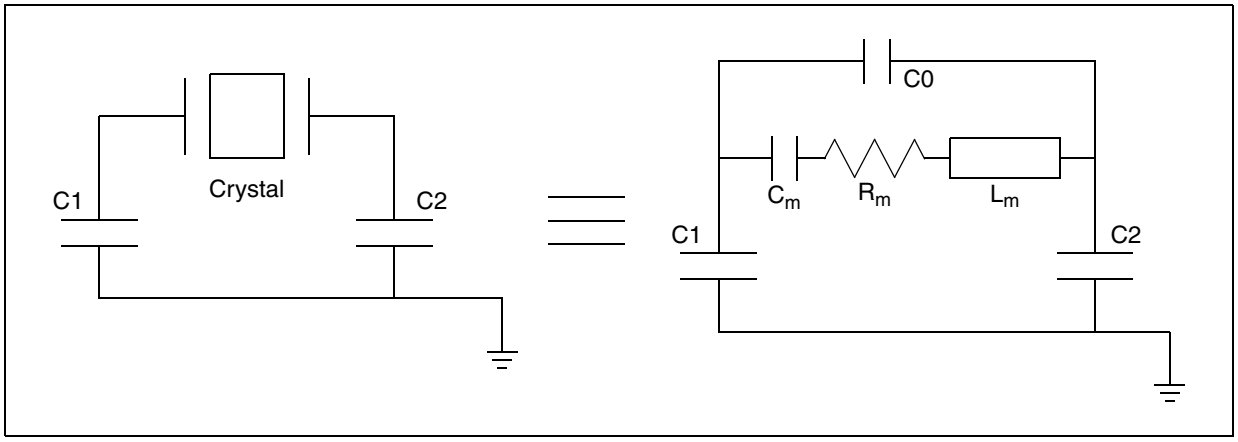


Figure 17. Equivalent circuit of a quartz crystal

Table 38. Crystal motional characteristics[1]

Symbol	Parameter	Conditions	Value			Unit
			Min	Typ	Max	
L_m	Motional inductance	—	—	11.796	—	KH
C_m	Motional capacitance	—	—	2	—	fF
C1/C2	Load capacitance at OSC32K_XTAL and OSC32K_EXTAL with respect to ground[2]	—	18	—	28	pF
R_m[3]	Motional resistance	AC coupled @ C0 = 2.85 pF[4]	—	—	65	kΩ
		AC coupled @ C0 = 4.9 pF[4]	—	—	50	
		AC coupled @ C0 = 7.0 pF[4]	—	—	35	
		AC coupled @ C0 = 9.0 pF[4]	—	—	30	

[1] Crystal used: Epson Toyocom MC306

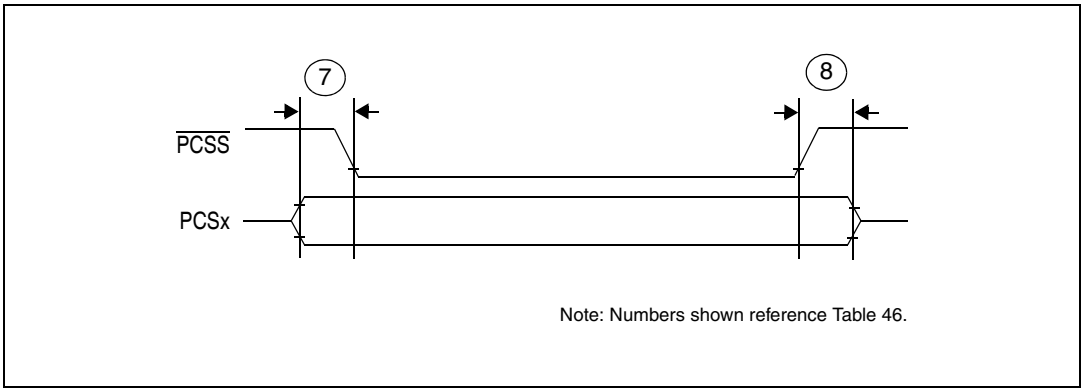


Figure 32. DSPI PCS strobe ($\overline{\text{PCSS}}$) timing

2.27.3 Nexus characteristics

Table 47. Nexus characteristics

No.	Symbol		C	Parameter	Value			Unit
					Min	Typ	Max	
1	t_{TCYC}	CC	D	TCK cycle time	64	—	—	ns
2	t_{MCYC}	CC	D	MCKO cycle time	32	—	—	ns
3	t_{MDOV}	CC	D	MCKO low to MDO data valid	—	—	8	ns
4	t_{MSEOV}	CC	D	MCKO low to MSEO_b data valid	—	—	8	ns
5	t_{EVTOV}	CC	D	MCKO low to EVTO data valid	—	—	8	ns
10	t_{NTDIS}	CC	D	TDI data setup time	15	—	—	ns
	t_{NTMSS}	CC	D	TMS data setup time	15	—	—	ns
11	t_{NTDIH}	CC	D	TDI data hold time	5	—	—	ns
	t_{NTMSH}	CC	D	TMS data hold time	5	—	—	ns
12	t_{TDOV}	CC	D	TCK low to TDO data valid	35	—	—	ns
13	t_{TDOI}	CC	D	TCK low to TDO data invalid	6	—	—	ns

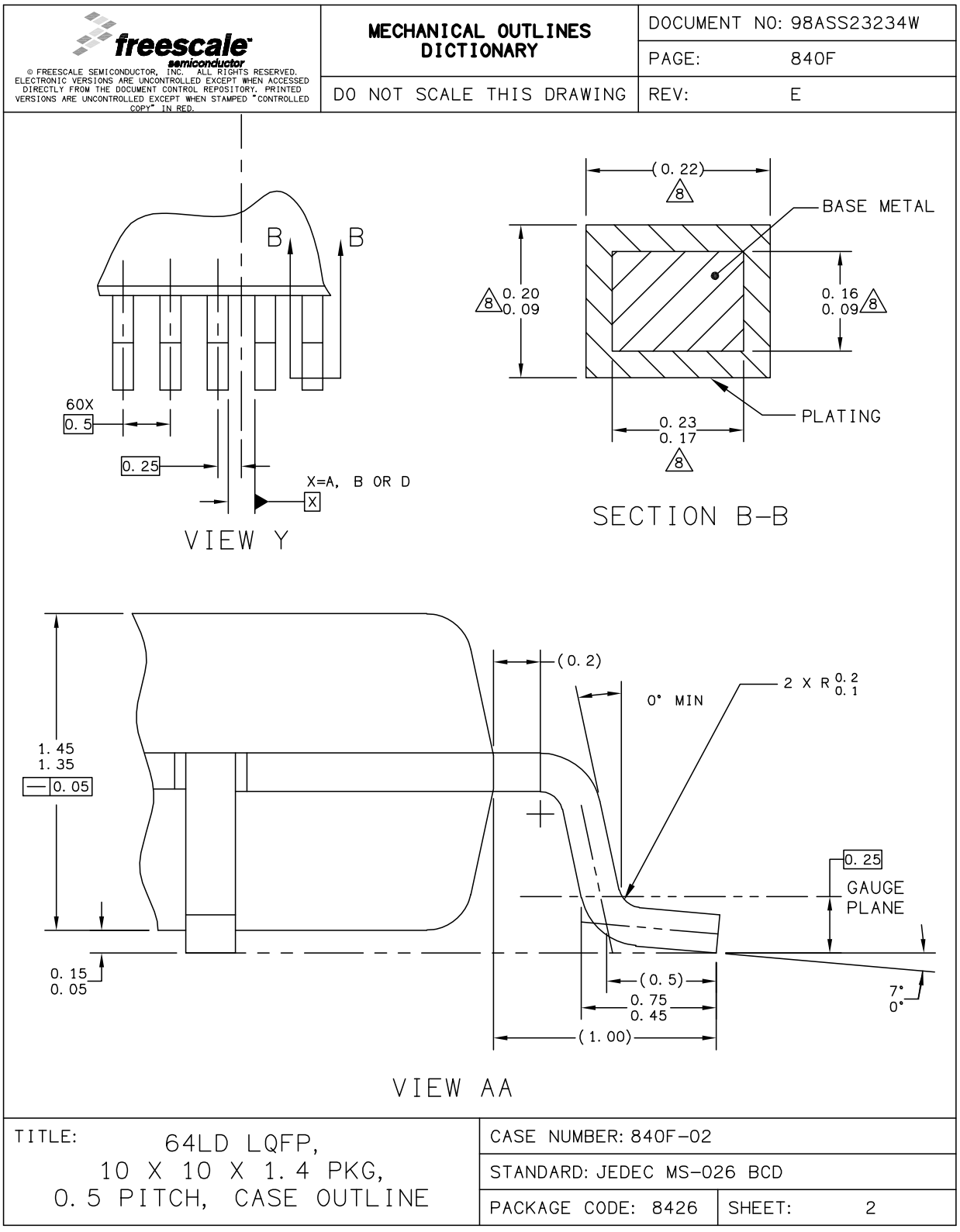


Figure 36. 64 LQFP package mechanical drawing (2 of 3)

freescale semiconductor	MECHANICAL OUTLINES DICTIONARY	DOCUMENT NO: 98ASS23234W
		PAGE: 840F
	DO NOT SCALE THIS DRAWING	REV: E

NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M–1994.
3. DATUMS A, B AND D TO BE DETERMINED AT DATUM PLANE H.
4. DIMENSIONS TO BE DETERMINED AT SEATING PLANE C.
5. THIS DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED THE UPPER LIMIT BY MORE THAN 0.08 mm AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSION AND ADJACENT LEAD SHALL NOT BE LESS THAN 0.07 mm.
6. THIS DIMENSION DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THIS DIMENSION IS MAXIMUM PLASTIC BODY SIZE DIMENSION INCLUDING MOLD MISMATCH.
7. EXACT SHAPE OF EACH CORNER IS OPTIONAL.
8. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.1 mm AND 0.25 mm FROM THE LEAD TIP.

TITLE: 64LD LQFP, 10 X 10 X 1.4 PKG, 0.5 PITCH, CASE OUTLINE	CASE NUMBER: 840F–02	
	STANDARD: JEDEC MS–026 BCD	
	PACKAGE CODE: 8426	SHEET: 3

Figure 37. 64 LQFP package mechanical drawing (3 of 3)

Table 49. Revision history (continued)

Revision	Date	Description of Changes
2	06-Mar-2009	Made minor editing and formatting changes to improve readability Harmonized oscillator naming throughout document Features: —Replaced 32 KB with 48 KB as max SRAM size —Updated description of INTC —Changed max number of GPIO pins from 121 to 123 Updated Section 1.2, Description Updated Table 3 Added Section 2, Block diagram Section 3, Package pinouts and signal descriptions: Removed signal descriptions (these are found in the device reference manual) Updated Figure 5: —Replaced VPP with VSS_HV on pin 18 —Added MA[1] as AF3 for PC[10] (pin 28) —Added MA[0] as AF2 for PC[3] (pin 116) —Changed description for pin 120 to PH[10] / GPIO[122] / TMS —Changed description for pin 127 to PH[9] / GPIO[121] / TCK —Replaced NMI[0] with NMI on pin 11 Updated Figure 4: —Replaced VPP with VSS_HV on pin 14 —Added MA[1] as AF3 for PC[10] (pin 22) —Added MA[0] as AF2 for PC[3] (pin 77) —Changed description for pin 81 to PH[10] / GPIO[122] / TMS —Changed description for pin 88 to PH[9] / GPIO[121] / TCK —Removed E1UC[19] from pin 76 —Replaced [11] with WKUP[11] for PB[3] (pin 1) —Replaced NMI[0] with NMI on pin 7 Updated Figure 6: —Changed description for ball B8 from TCK to PH[9] —Changed description for ball B9 from TMS to PH[10] —Updated descriptions for balls R9 and T9 Added 2.10, Parameter classification and tagged parameters in tables where appropriate Added 2.11, NVUSRO register Updated Table 11 2.13, Recommended operating conditions: Added note on RAM data retention to end of section Updated Table 12 and Table 13 Added 2.14.1, Package thermal characteristics Updated 2.14.2, Power considerations Updated Figure 7

Table 49. Revision history (continued)

Revision	Date	Description of Changes
2 (cont.)	06-Mar-2009	Updated Table 15, Table 16, Table 17, Table 18 and Table 19 Added 2.15.4, Output pin transition times Updated Table 22 Updated Figure 8 Updated Table 24 2.17.1, Voltage regulator electrical characteristics: Amended description of LV_PLL Figure 10: Exchanged position of symbols C_{DEC1} and C_{DEC2} Updated Table 25 Added Figure 13 Updated Table 26 and Table 27 Updated 2.19, Flash memory electrical characteristics Added 2.20, Electromagnetic compatibility (EMC) characteristics Updated 2.21, Fast external crystal oscillator (4 to 16 MHz) electrical characteristics Updated 2.22, Slow external crystal oscillator (32 kHz) electrical characteristics Updated Table 40, Table 41 and Table 42 Added 2.27, On-chip peripherals Added Table 43 Updated Table 44 Updated Table 47 Added Appendix A, Abbreviations
4	06-Aug-2009	Updated Figure 6 Table 11 • V_{DD_ADC}: changed min value for “relative to V_{DD}” condition • V_{IN}: changed min value for “relative to V_{DD}” condition • I_{CORELV}: added new row Table 13 • $T_{A\ C\text{-}Grade\ Part}$, $T_{J\ C\text{-}Grade\ Part}$, $T_{A\ V\text{-}Grade\ Part}$, $T_{J\ V\text{-}Grade\ Part}$, $T_{A\ M\text{-}Grade\ Part}$, $T_{J\ M\text{-}Grade\ Part}$: added new rows • Changed capacitance value in footnote Table 20 • MEDIUM configuration: added condition for PAD3V5V = 0 Updated Figure 10 Table 25 • C_{DEC1}: changed min value • $I_{MREG:}$ changed max value • I_{DD_BV}: added max value footnote Table 26 • $V_{LVDHV3H}$: changed max value • $V_{LVDHV3L}$: added max value • $V_{LVDHV5H}$: changed max value • $V_{LVDHV5L}$: added max value Updated Table 27 Table 29 • Retention: deleted min value footnote for “Blocks with 100,000 P/E cycles“ Table 37 • I_{FXOSC}: added typ value Table 39 • V_{SXOSC}: changed typ value • $T_{SXOSCSU}$: added max value footnote Table 40 • Δt_{LTJIT}: added max value Updated Figure 38

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Document Number: MPC5604BC
Rev. 14
11/2017